

# X-ray Optics Development at NASA MSFC

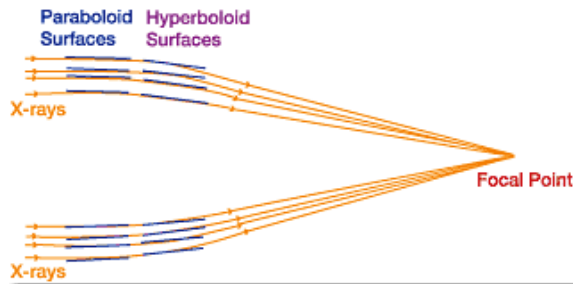
D. Broadway

# Talk Outline

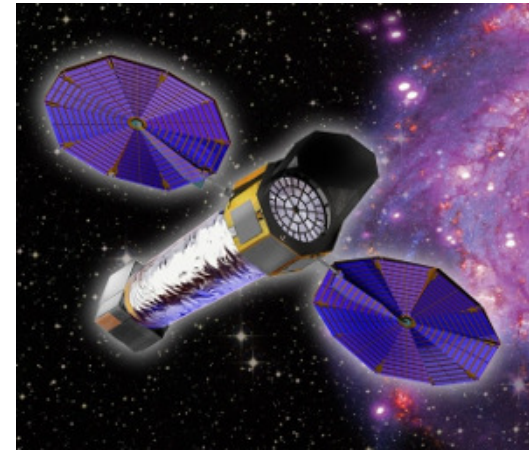


- X-ray optics for space-borne applications
- Electroformed NiCo X-ray optics at MSFC
- Thin film coatings to enhance X-ray optical performance
- Thin film stress
- In-situ film stress measurement at MSFC: from prototype to refined design
- Ultra lightweight aerogel mirrors

# X-ray optics for space-borne applications (Wolter I)



Segments assembled into full shells



Lynx will require 37,492 segments!  
Segments are only  $\sim 400 \mu\text{m}$  thick!



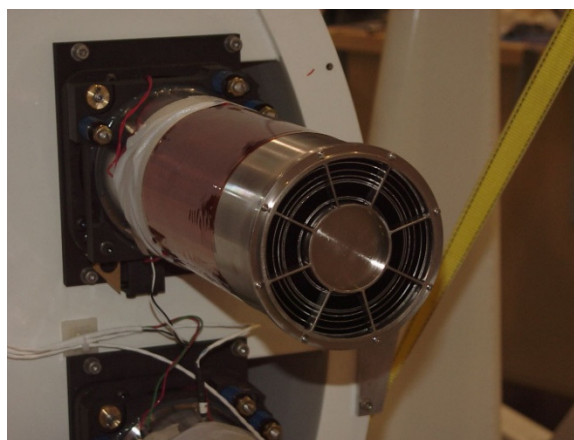
# Electroformed X-ray optics at MSFC



Down to 50 $\mu$ m thick



Up to 0.5 m diameter

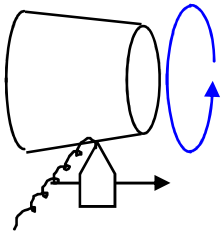


Down to 0.025 m diameter

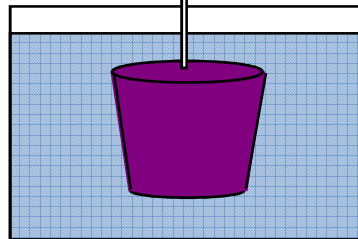
# Electroforming replication process at MSFC



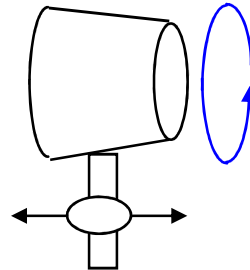
**1. CNC Machine,  
Mandrel Formation  
From Al Bar**



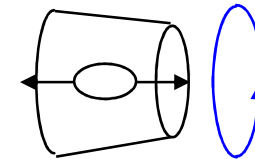
**2. Chemical Clean  
and Activation  
& Electroless Nickel  
(EN) plate**



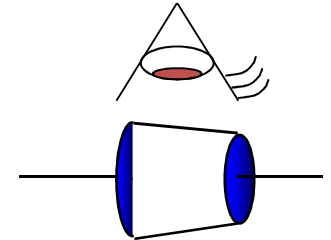
**3. Precision Turn  
to 600Å, sub-  
micron figure  
accuracy**



**4. Polish and  
Superpolish to  
3 - 4Å rms finish**

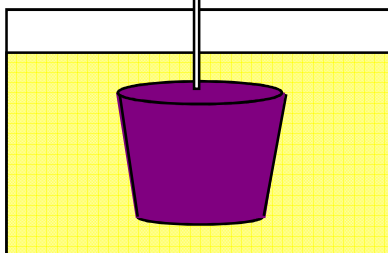


**5. Metrology  
On Mandrel**

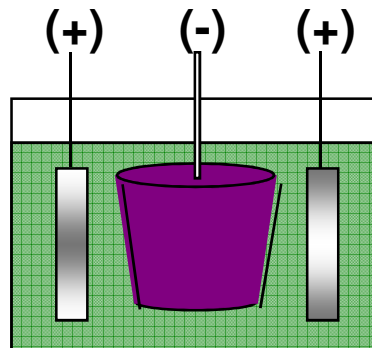


## Shell Fabrication

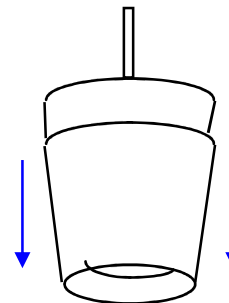
**6. Ultrasonic clean  
and Passivation to  
Remove Surface  
Contaminants**



**7. Electroform Ni/Co  
Shell onto Mandrel**



**8. Separate Optic  
From Mandrel in  
Cold Water Bath**

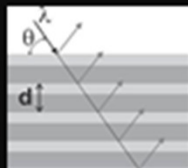


# Thin film coatings to enhance X-ray reflectivity

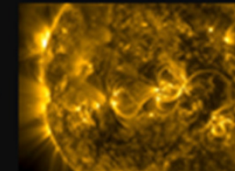
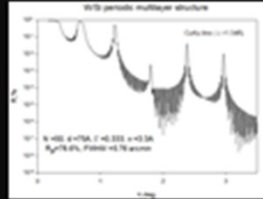


## Multilayer thin-film reflective coatings

- Needed to efficiently reflect light at the high-energy region of the spectrum, from EUV to hard x-rays.
- Periodic multilayers are used as selective optical elements due their inherently narrow spectral response.
- At EUV energies they can be designed to reflect at normal incidence.
- Enabled the fabrication of Cassegrain-type EUV reflecting telescopes.

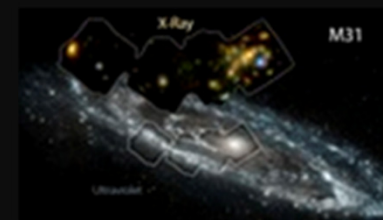
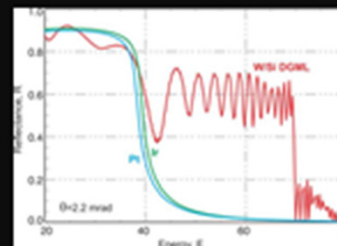
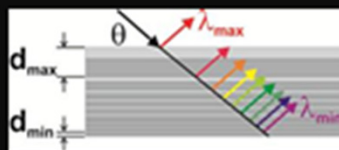


A periodic multilayer



Taken by SDO/AIA

- A depth-graded multilayers is a film stack containing a range of layer thicknesses
- They are designed to give a spectral response at grazing incidence this is several times broader than the total external reflection regime of a single layer films.



Taken by NuSTAR

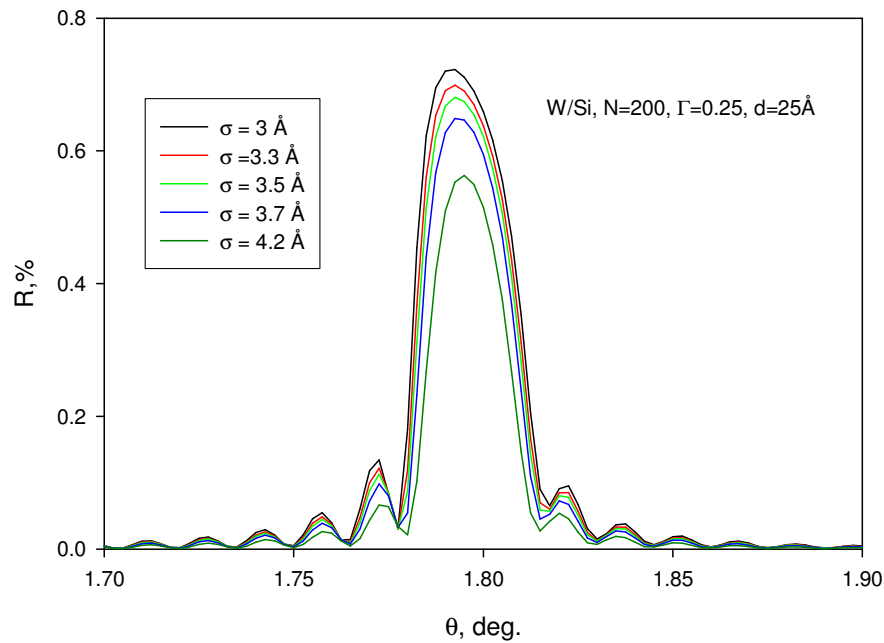
The stress in these coatings will severely deform thin, precisely figured substrates and degrade imaging quality

# X-ray reflectivity from the multilayer

Modified Fresnel coefficient:

$$r = r_0 e^{-\frac{8\pi^2 \sigma^2}{\lambda^2} \sin^2(\theta_0)}$$

Roughness influence on first order reflectivity



$$r_{N-j}^s = \frac{\sqrt{n_{N-j}^2(\lambda) - \cos^2(\theta_0)} - \sqrt{n_{N-j+1}^2(\lambda) - \cos^2(\theta_0)}}{\sqrt{n_{N-j}^2(\lambda) - \cos^2(\theta_0)} + \sqrt{n_{N-j+1}^2(\lambda) - \cos^2(\theta_0)}}$$

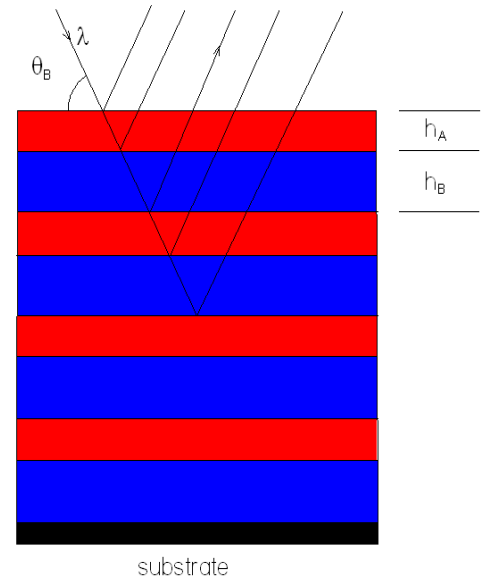
$$r_{N-j}^p = \frac{\left(\frac{n_{N-j}(\lambda)}{n_{N-j+1}(\lambda)}\right) \sqrt{n_{N-j+1}^2(\lambda) - \cos^2(\theta_0)} - \sqrt{n_{N-j}^2(\lambda) - \cos^2(\theta_0)}}{\left(\frac{n_{N-j}(\lambda)}{n_{N-j+1}(\lambda)}\right) \sqrt{n_{N-j+1}^2(\lambda) - \cos^2(\theta_0)} + \sqrt{n_{N-j}^2(\lambda) - \cos^2(\theta_0)}}$$

$$\beta_{N-j} = \frac{2\pi h_{N-j}}{\lambda} \sqrt{1 - \frac{\cos^2(\theta_0)}{n_{N-j+1}^2(\lambda)}}$$

$$S_{j+1}^v = \frac{r_{N-j}^v + S_j^v e^{2i\beta_{N-j}}}{1 + r_{N-j}^v S_j^v e^{2i\beta_{N-j}}}$$

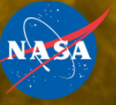
$$R = \frac{1}{2} R^s + \frac{1}{2} R^p$$

$$R^v = S^v S^{v*}$$



$$d \equiv h_A + h_B$$

# Thin Film Stress



- The stress can be compressive or tensile.
- Various components of stress:
  - Intrinsic,  $\sigma_i$ , which is related to the film's microstructure.
  - Thermal stress,  $\sigma_{\Delta CTE}$ , which arises due to the difference in the linear expansion coefficient between the film and substrate and the difference between substrate temperature,  $T_s$ , during deposition and subsequent cooling to room temperature:  
$$\sigma_{\Delta CTE} = M_f(\alpha_s - \alpha_f)\Delta T$$
  - Extrinsic,  $\sigma_{ext}$ , that results due to external forces applied to the film substrate system such as bending of the substrate to produce a figured optic.
- The film stress can be enormous for some materials (i.e. GPa's)
- The curvature,  $\kappa$ , of the deformed substrate is proportional to the product of film stress and film thickness,  $\sigma h_f$ , through a constant that describes the geometric and mechanical properties of the substrate (Stoney's Equation)--namely, the substrate's thickness,  $h_s$ , and biaxial modulus,  $\frac{E_s}{(1-\nu_s)}$ :

$$\sigma h_f = \frac{E_s h_s^2}{6(1 - \nu_s)} \kappa$$

N/m



# Thin Film Stress (Cont'd)



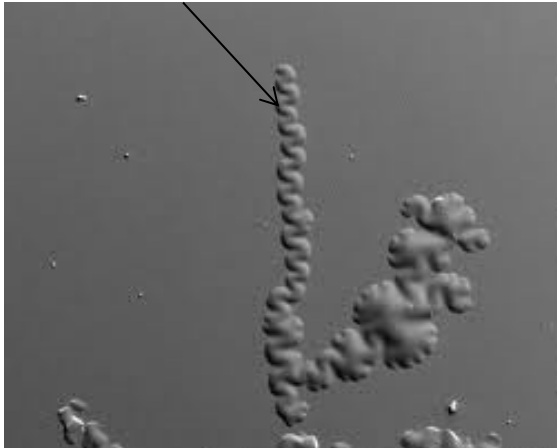
- In controlling film stress, the aim is to manipulate the energy of the sputtered atoms and influence the adatom mobility at the film surface.
- For a given material, stress is highly process dependent for magnetron sputtering and influenced by deposition conditions:
  - Gas Pressure (stress reversal)
  - Deposition Rate (cathode power)
  - Substrate Temperature
  - Substrate bias
- There is a trade-off between film stress and film quality (i.e. roughness, density).
  - Generally, the deposition conditions needed to achieve good X-ray reflectivity result in high film stress.

# Detrimental effects of high film stress:

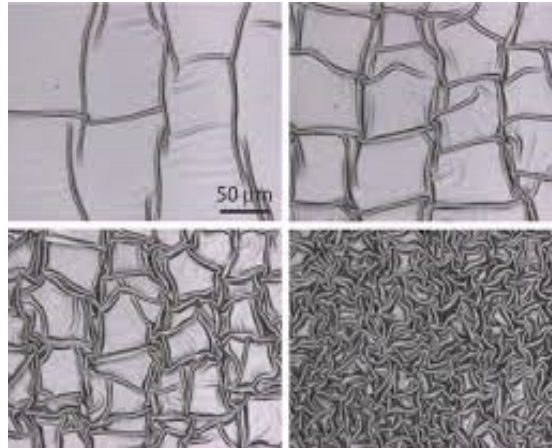


- Cracking, buckling and delamination  
If the force per unit length due to the stress in the film exceeds the adhesive force, delamination of the film will occur.

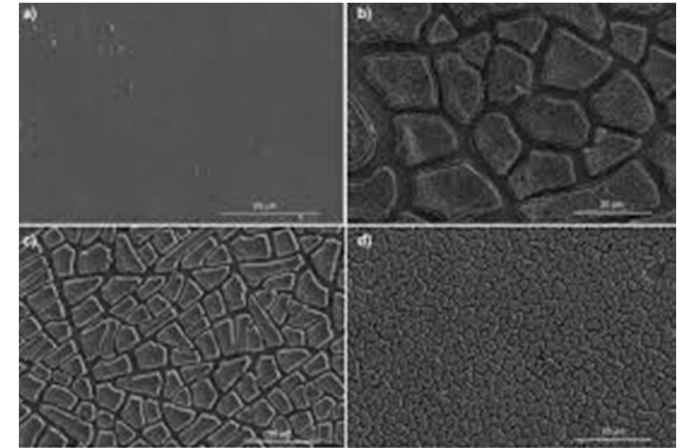
“telephone chord” propagation



High compressive stress (buckling)

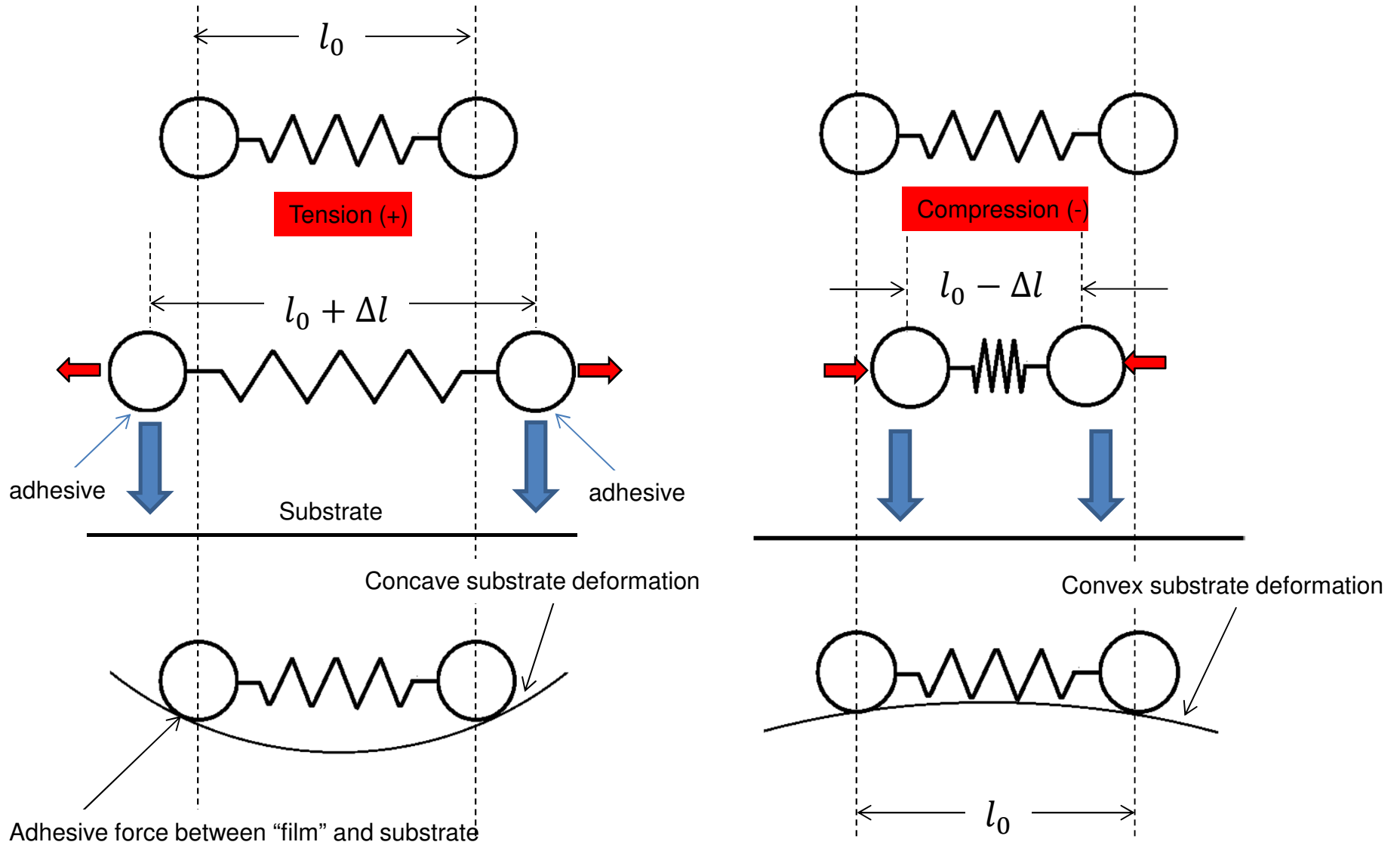


High tensile stress (cracking)



- Substrate deformation
  - Of particular concern for grazing incidence X-ray optics since the stress can alter the precise geometrical figure and degrade its focusing or collimating properties.
    - Significant technological challenge for the next generation of lightweight X-ray space telescopes like Lynx:
      - The desire to achieve sub-second resolution has motivated deposition techniques to correct substrate figure errors which rely on a very low stress film (ie. A few MPa)
      - Substrates are only 10's of microns thick.
      - The X-ray reflective Ir layer is highly stressed (~4 GPa)

# Stress/Spring Model



The film will delaminate if the stress is greater than the adhesion between the film as substrate

# Measurement of thin film stress (ex-situ)

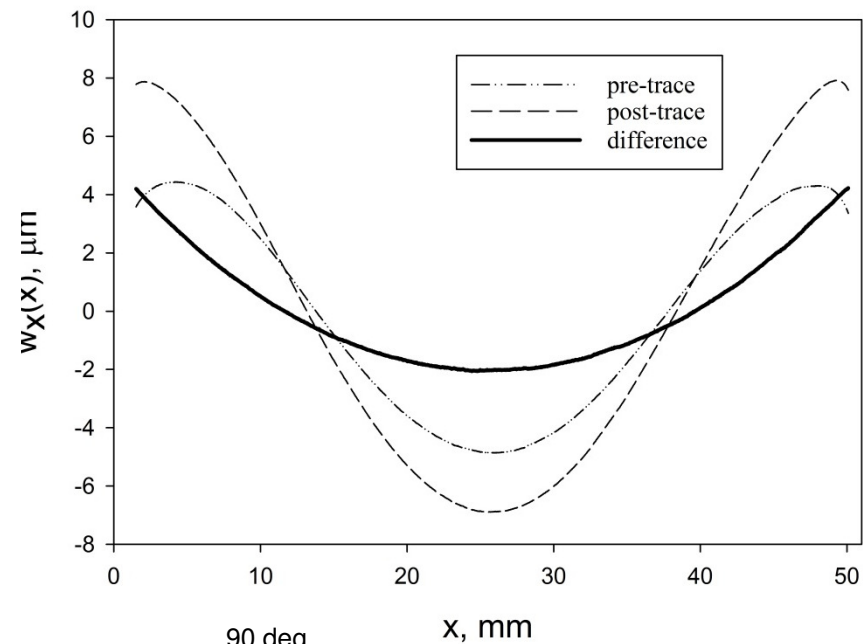
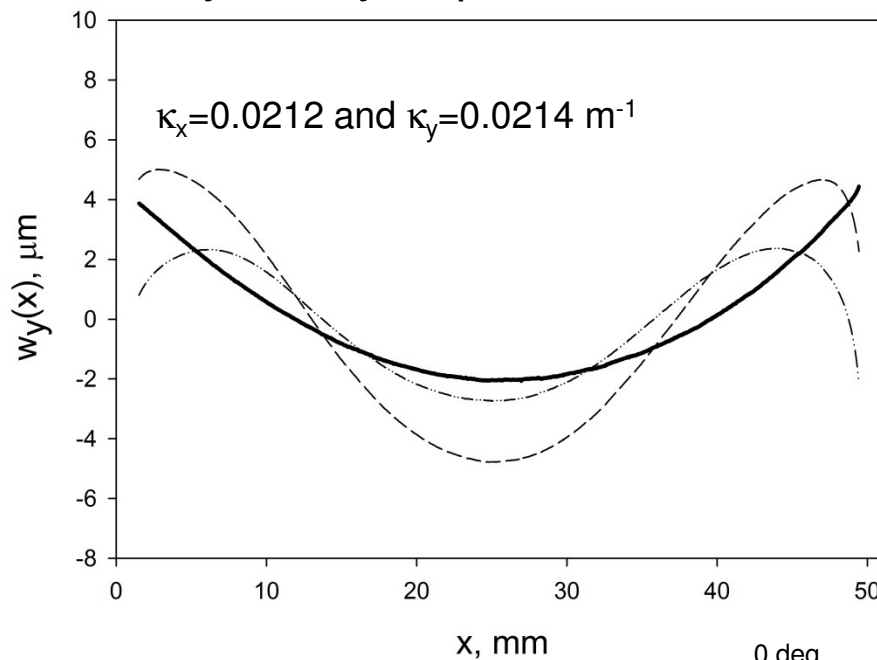


$$\text{Stoney's Eqn: } \sigma h_f = \frac{E_s h_s^2}{6(1 - \nu_s)} \kappa$$

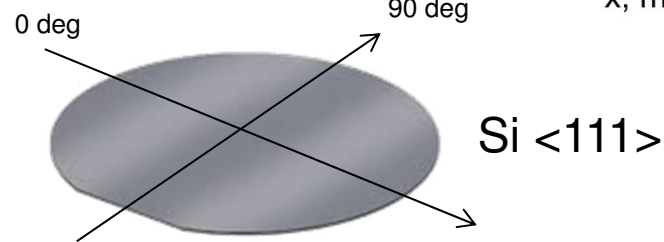
Spherical Deformation Mode:

$$A = \sigma h_f \frac{D_s^2}{h_s^3}$$

Tallysurf stylus profilometer



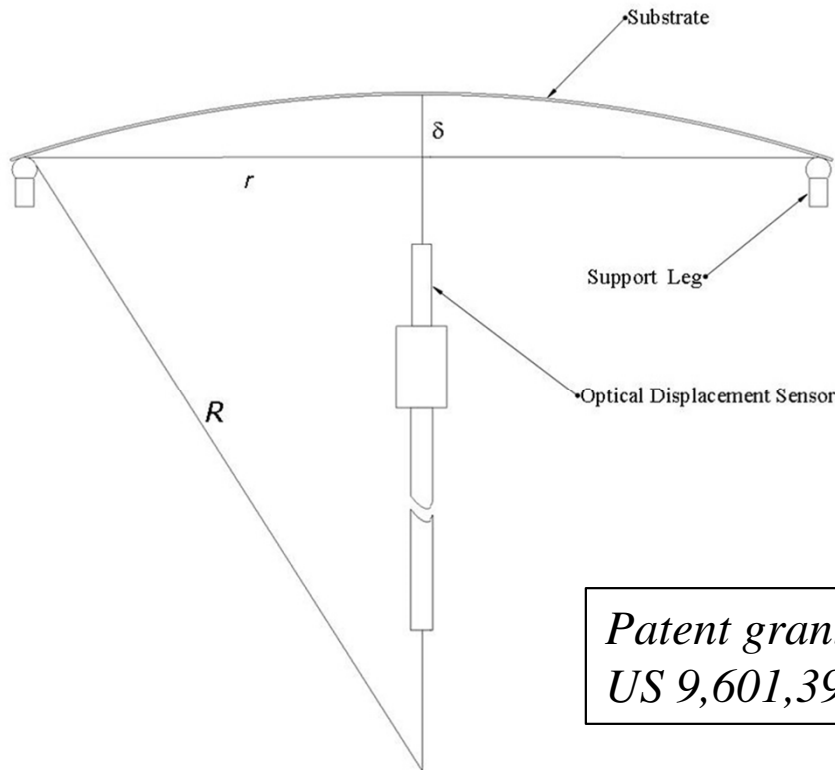
$$\kappa \approx \frac{d^2 w}{d^2 x} = \text{const}$$



# MSFC In-Situ stress measurement methodology:

Since substrate deformation is spherical we need only measure the sag,  $\delta$ , to infer its curvature.

$$\sigma h_f = \frac{E_s h_s^2}{6(1 - \nu_s)} \kappa \quad , \text{where} \quad \kappa = \frac{2\delta}{r^2 + \delta^2} \quad \xrightarrow{r \approx \frac{D_s}{2} \gg \delta} \quad \sigma h_f = \frac{4}{3} \frac{E_s}{(1 - \nu_s)} \left( \frac{h_s}{D_s} \right)^2 \delta$$

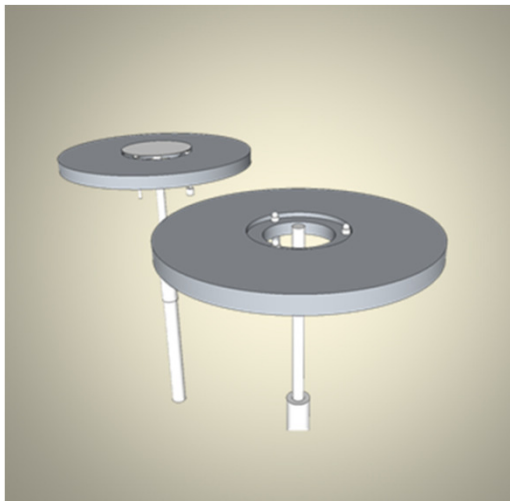
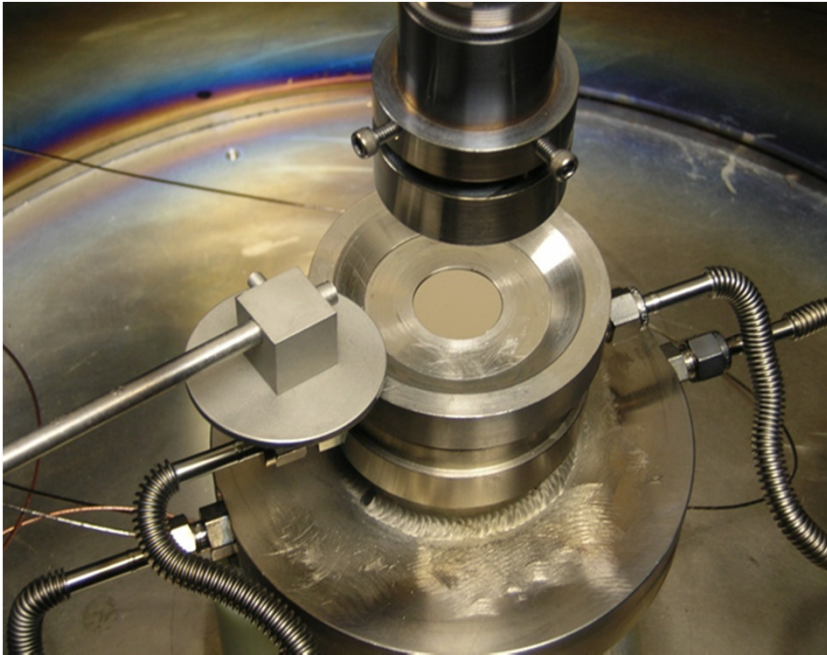


The curvature measurement is performed during deposition by measuring the backside of a double side polished substrate with a non-contact variation of the classic spherometer using a high resolution fiber optic displacement sensor.

*Patent granted:  
US 9,601,391 B2*



# The prototype



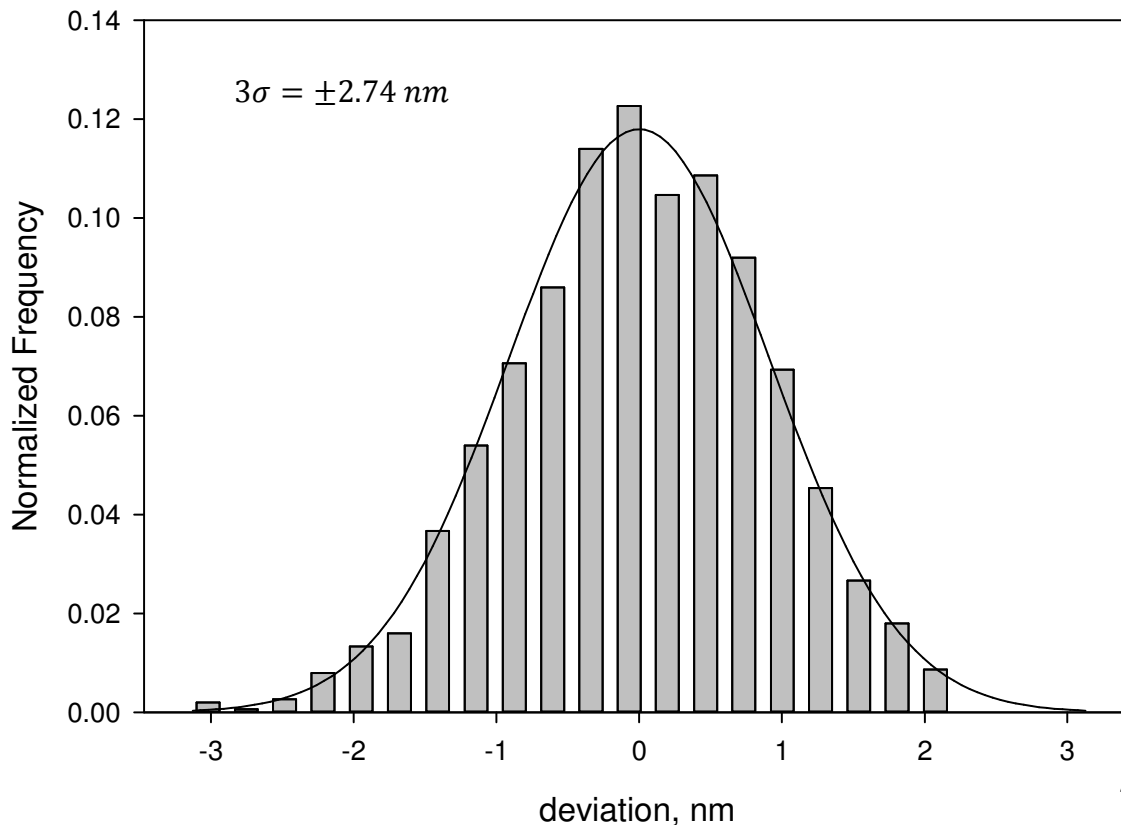
# Stress Measurement Resolution (circular substrate):



Minimum force per unit width:

$$\Delta(\sigma h_f) = \frac{4}{3} \frac{E_s}{(1 - \nu_s)} \left( \frac{h_s}{D_s} \right)^2 \Delta\delta$$

Fiber Optic Random Noise Distribution



Minimum force per unit width for 280  $\mu\text{m}$  Si <111>, 1 in. dia. substrate:

$$\Delta(\sigma h_f) = 15 \text{ MPa} * \text{nm}$$



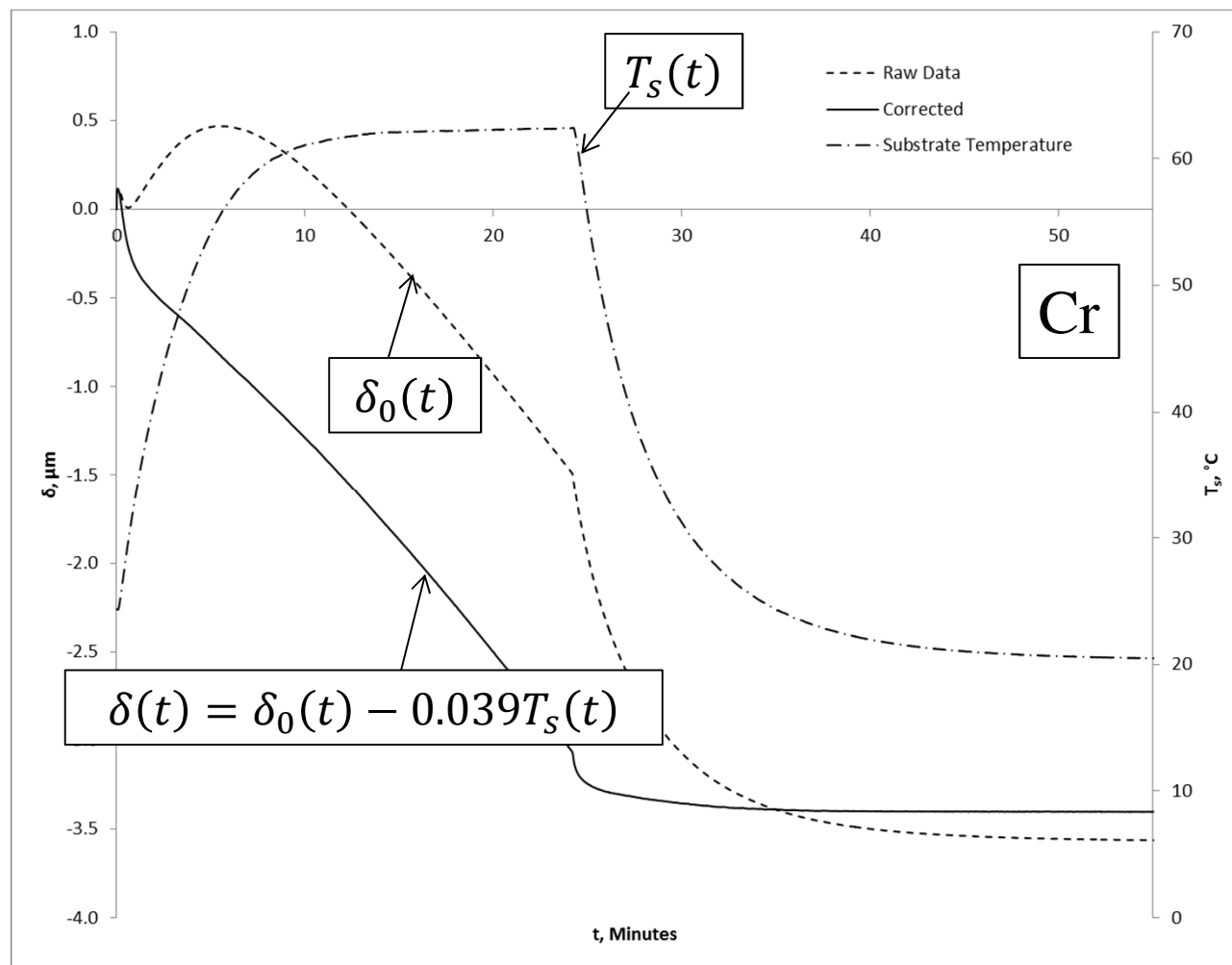
This means for example that:  
A film with  $\sigma_i = 100 \text{ MPa} \Rightarrow$   
 $\Delta h_f = 6.7 \text{ nm}$

For smaller values of stress, we can enhance the sensitivity by utilizing thinner substrates.

$$\sigma h_f = \left( \frac{h}{h_0} \right)^2 (\sigma h_f)_0$$

$\Delta h_f = 8.5 \text{ \AA}$  for 100  $\mu\text{m}$  substrate

# Raw data must be corrected for thermal expansion error





# Measured data corrected for systematic thermal error



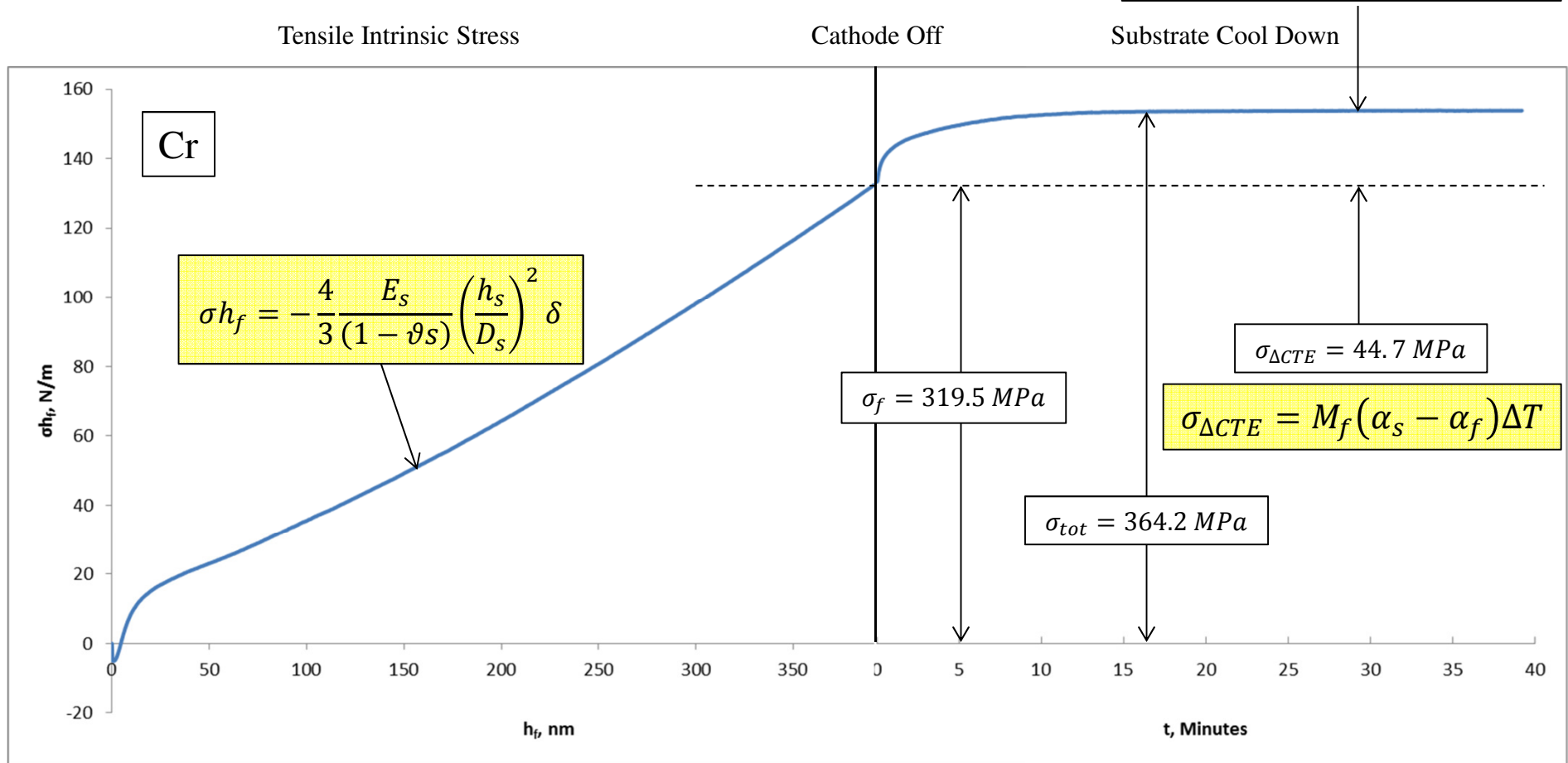
As a check of the results we can compare the measured contribution of the stress resulting from the mismatch in the thermal expansion coefficient between the film as substrate,  $\sigma_{\Delta CTE}$ , to the calculated value using bulk constants for chromium to:

$$\sigma_{\Delta CTE}^{calc} = 46.8 \text{ MPa}$$

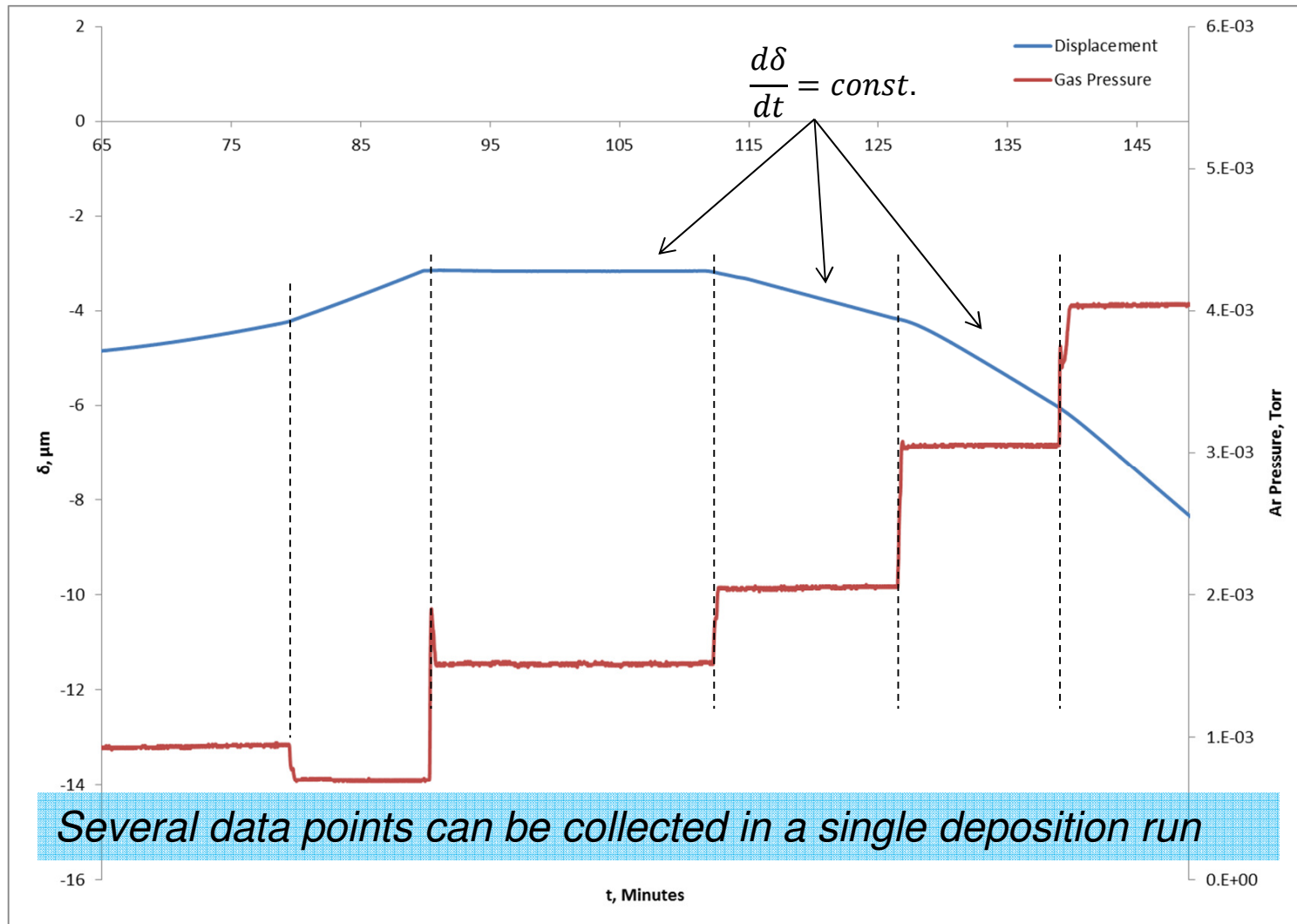
$$\sigma_{\Delta CTE}^{measured} = 44.7 \text{ MPa}$$

With:  $M_f = 279 \text{ GPa}$ ,  $\alpha_f = 6.2 \times 10^{-6} \text{ }^\circ\text{C}^{-1}$ ,  $\alpha_s = 2.2 \times 10^{-6} \text{ }^\circ\text{C}^{-1}$ ,  $\Delta T = 42 \text{ }^\circ\text{C}$

Agreement to within 4.5%



# Variation of instantaneous stress with Ar process pressure



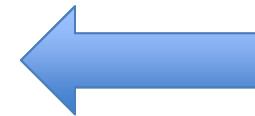
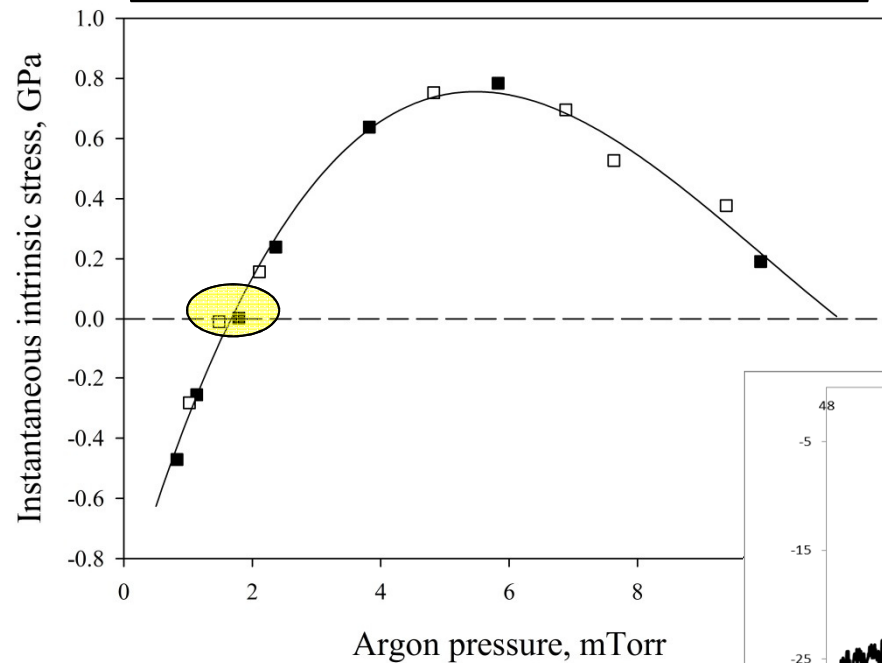
# Stress reversal in metal films



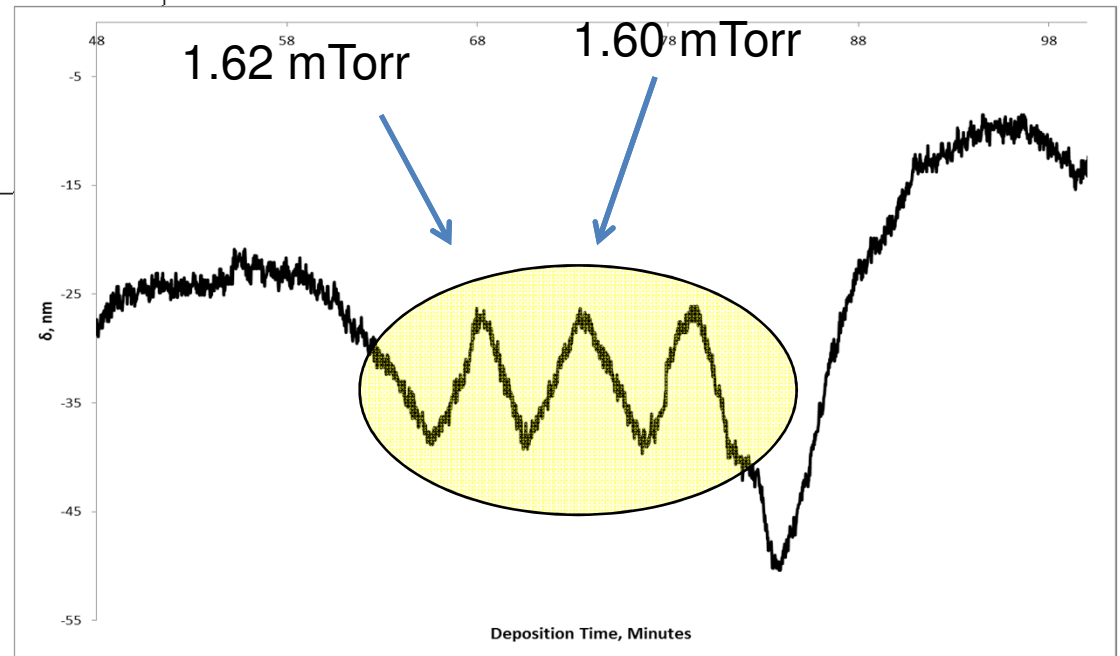
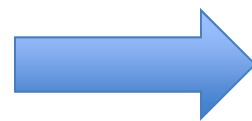
$$\frac{d(\sigma h_f)}{dh_f} = -\frac{E_s}{3\xi(1-\nu_s)} \left(\frac{h_s}{r}\right)^2 \frac{d\delta}{dt}$$

Results are consistent with D.W. Hoffman, *Internal stress of sputtered Chromium, Thin Solid Films, 40 (1977) 355-363*

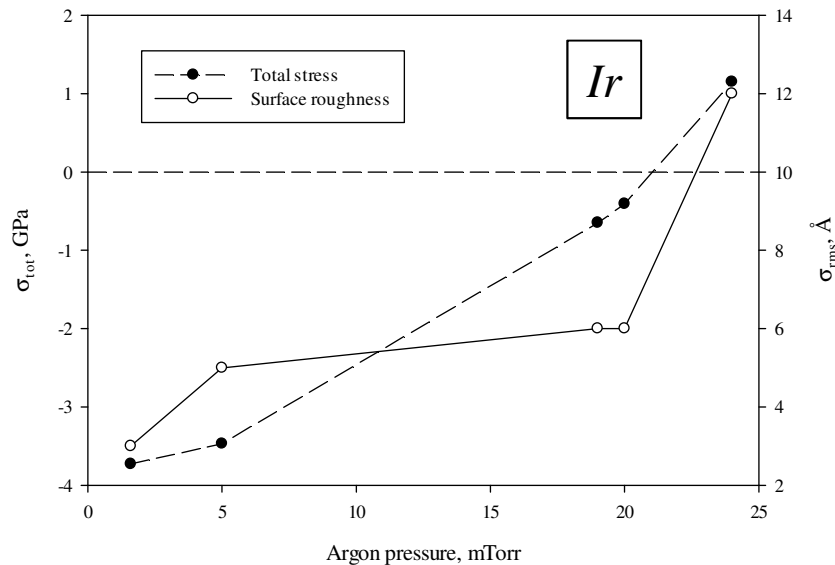
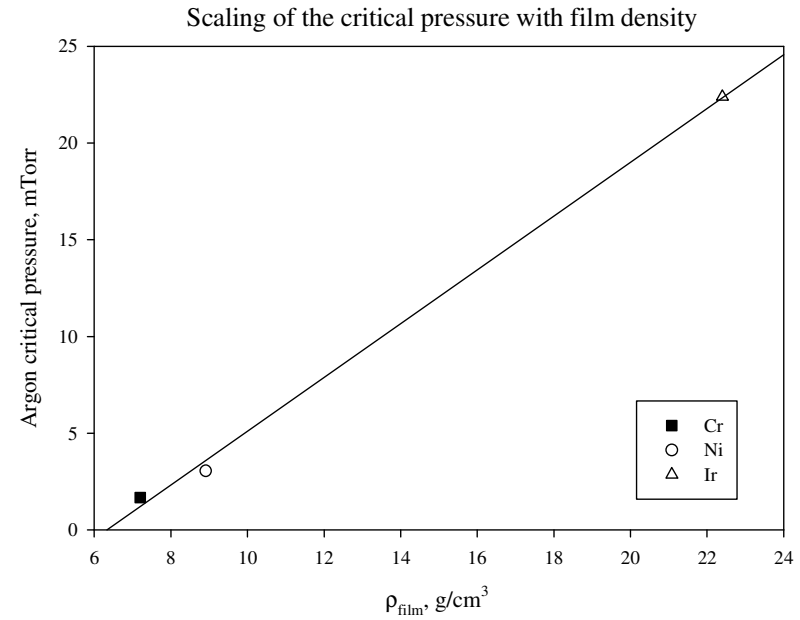
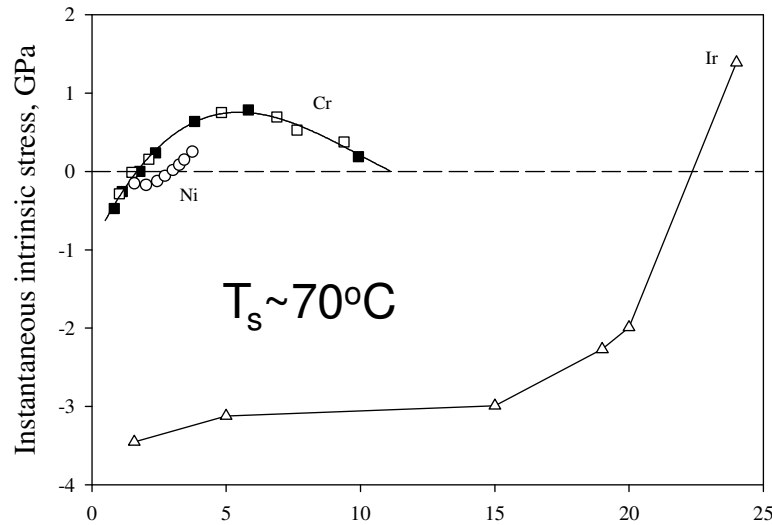
Stress reversal in Cr with argon pressure has been measured with the instrument. Consistent with the previous work of Hoffman (i.e. stress reversal).



Measurement sensitivity is better than resolution in the control of Argon pressure.



# Stress reversal cond't

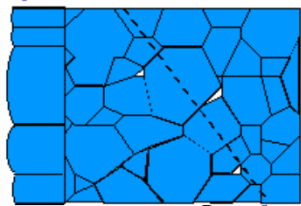


- Iridium exhibits stress reversal at high argon pressure ( $\sim 22$  mTorr)
- At this pressure the film's microstructure causes surface roughness that exceeds the tolerable limit of 4-5  $\text{\AA}$  for soft X-rays
- We can't use the stress reversal mechanism to achieve zero stress in Ir films

# Film stress and microstructure



Island coalescence



Type I  
high  $T_m$   
low atomic mobility

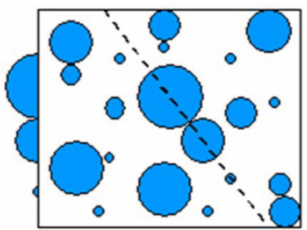
Type II  
low  $T_m$   
high atomic mobility

force per unit width

thickness

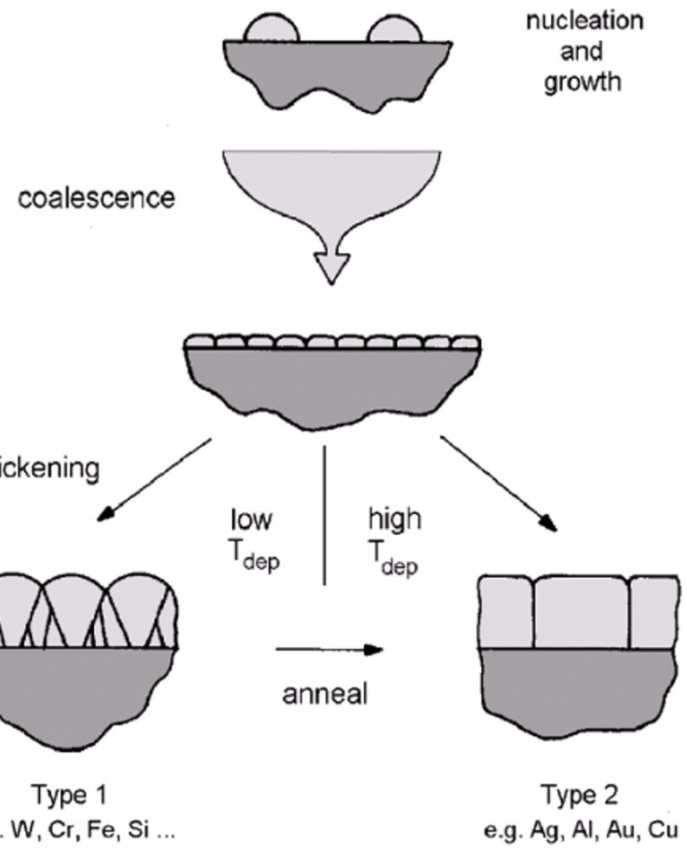
tensile  
compressive

Volmer-Weber Growth Mode



Nucleation & island growth

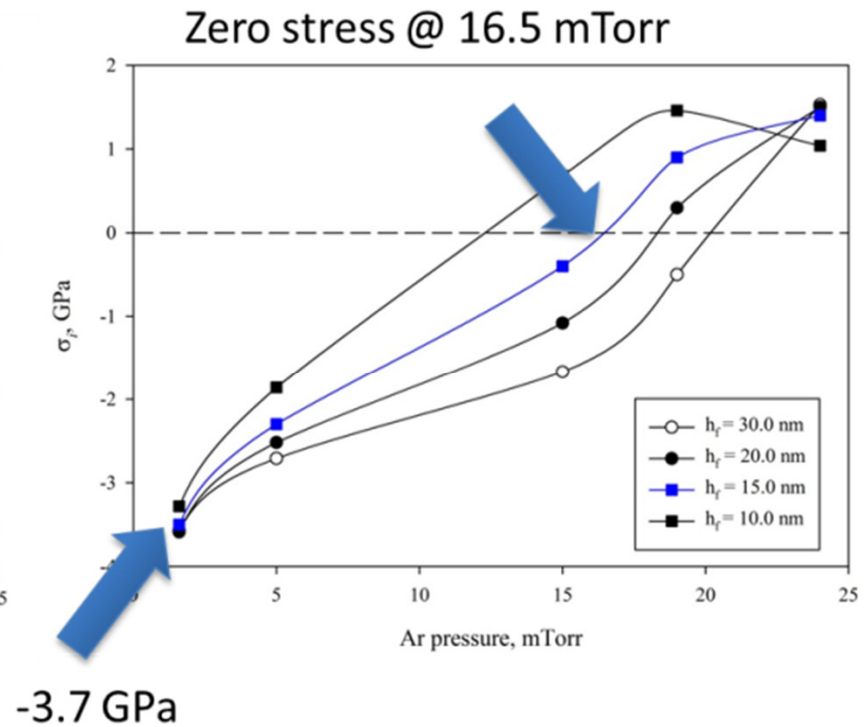
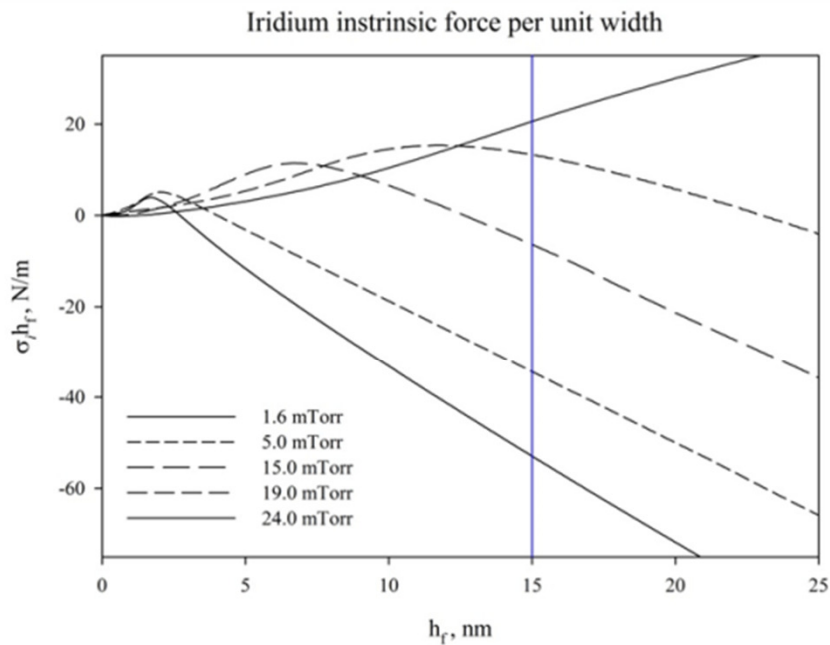
Depends on:  
Substrate temperature  
Argon pressure  
Mass of sputtered atoms  
Substrate bias  
Surface energy



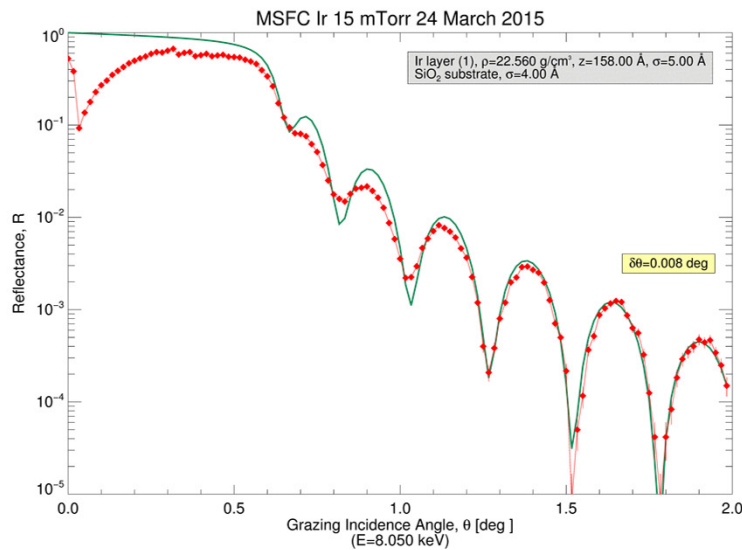
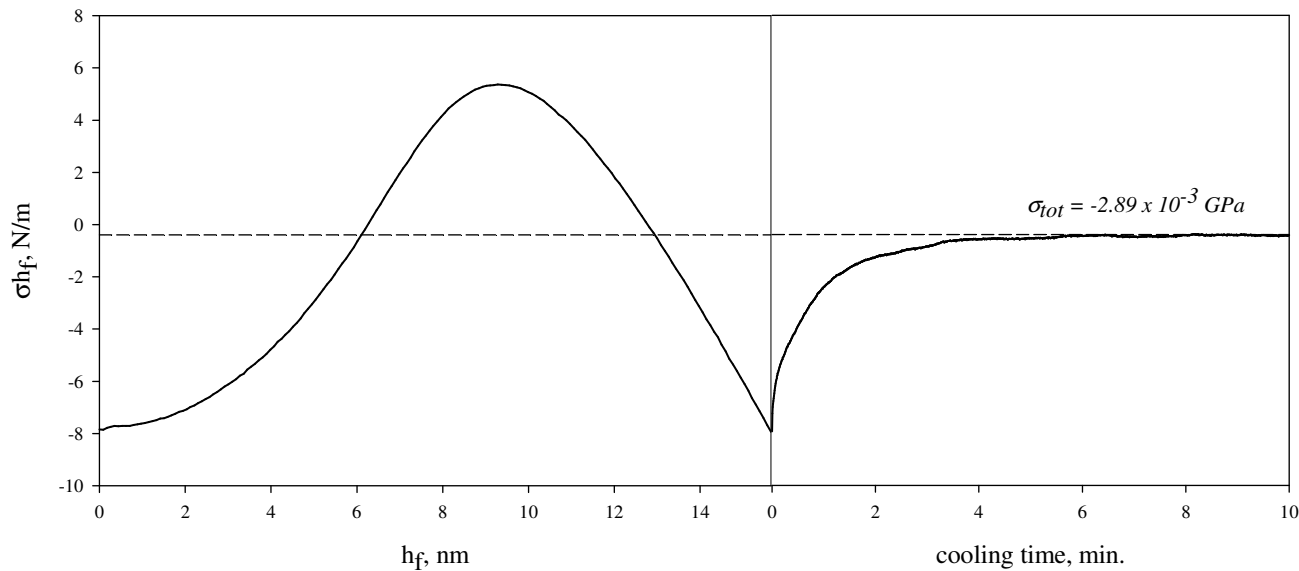
Surface roughness increases with film thickness

Low surface roughness

# Stress in Iridium



# Near-zero stress in Iridium



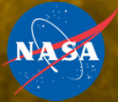
Reduction in the total stress by 3 orders of magnitude (i.e. to -2.89 MPa)

Good adhesion

Promising result: 5Å rms roughness

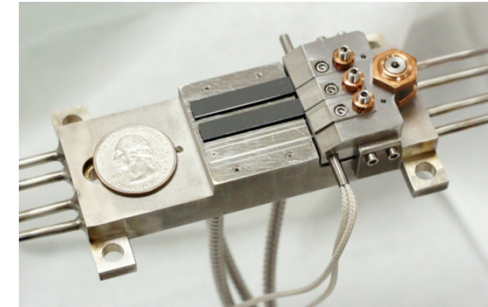
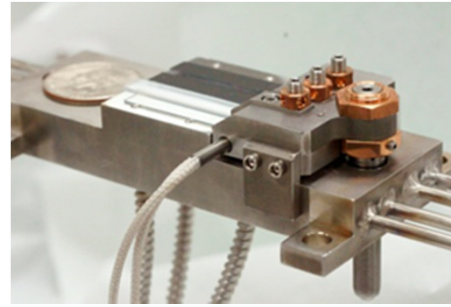
Further reduction in the roughness is possible through optimization of Ar pressure

# Refined approach: Cantilever substrate

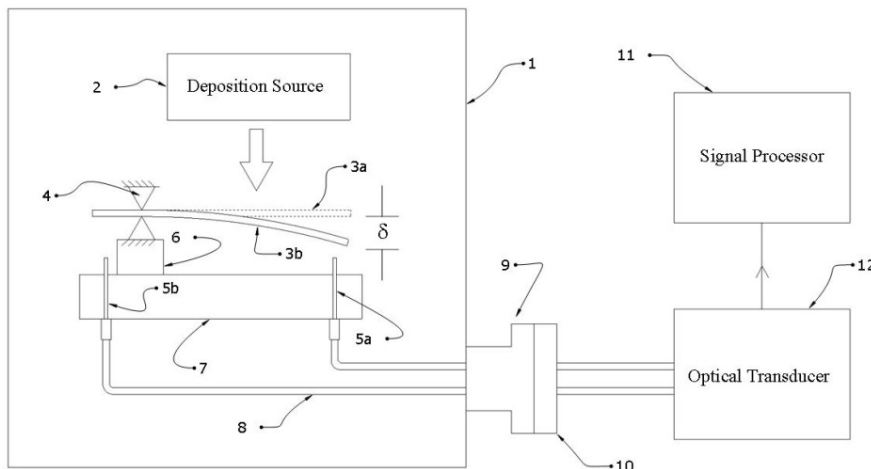


Stoney Eqn. for cantilever:

$$\sigma h_f = \frac{E_s h_s^2 \delta}{3(1 - \nu_s) L^2}$$

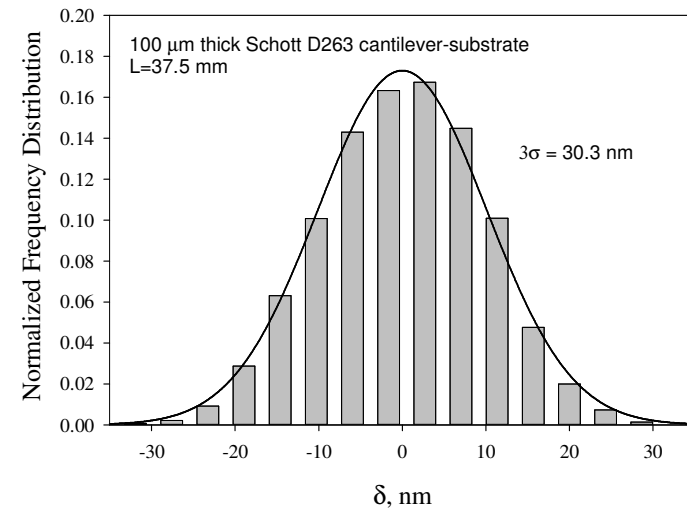


$$\Delta(\sigma h_f) = 9 \text{ MPa} * \text{nm}$$



- The use of cantilever substrates can theoretically provide a four fold increase in measurement sensitivity in comparison to circular substrates of a similar thickness and characteristic dimension ( $D_s \sim L$ )
- The vibrational noise, however, also increases resulting only in a factor of  $\sim 1.7$  improvement.

*D.M. Broadway, U.S. Patent 9,601,391 (Granted March 2017).*  
*D.M. Broadway, U.S. Patent Application 15/425,740 (Filed February 2017).*





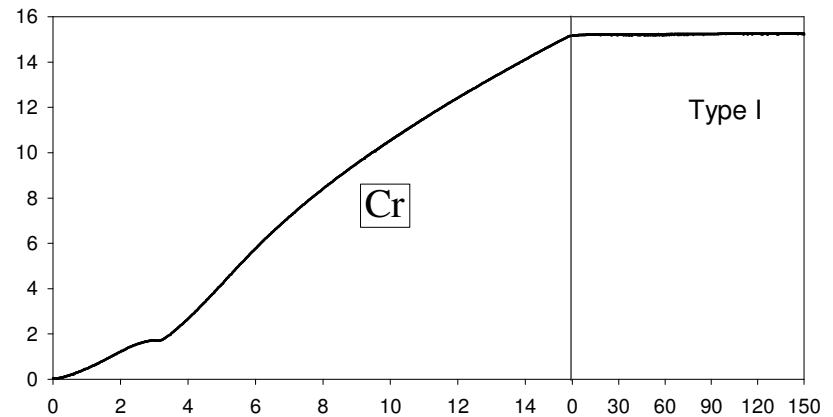
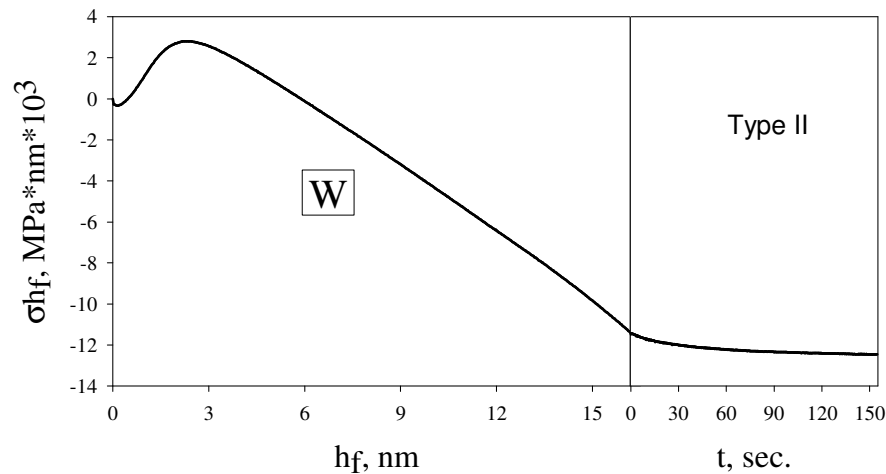
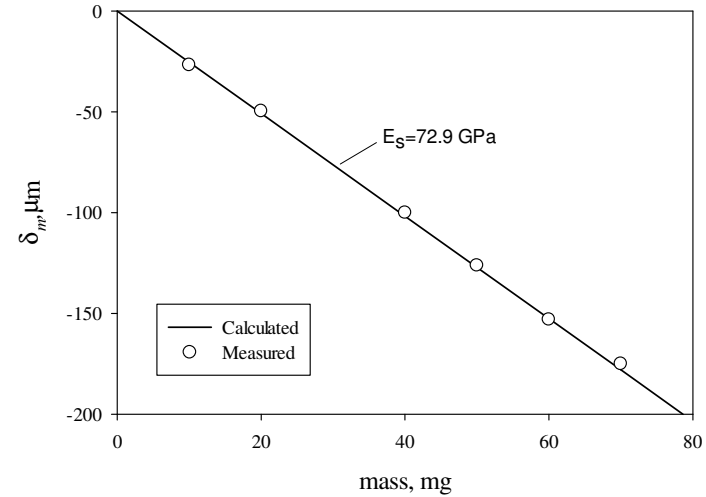
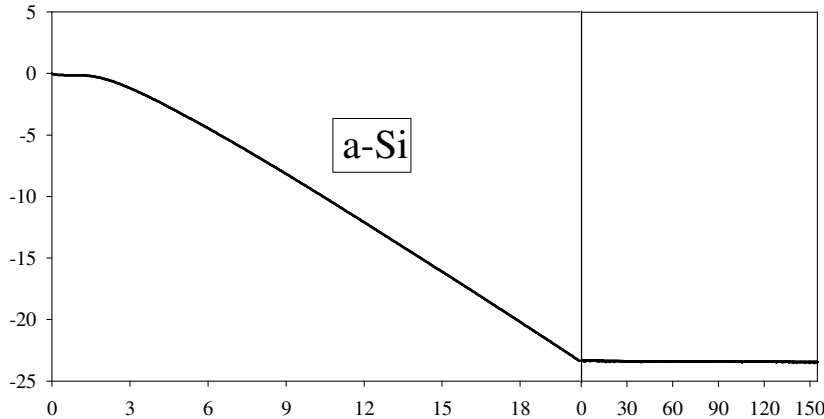
# In-situ stress of single layer thin films



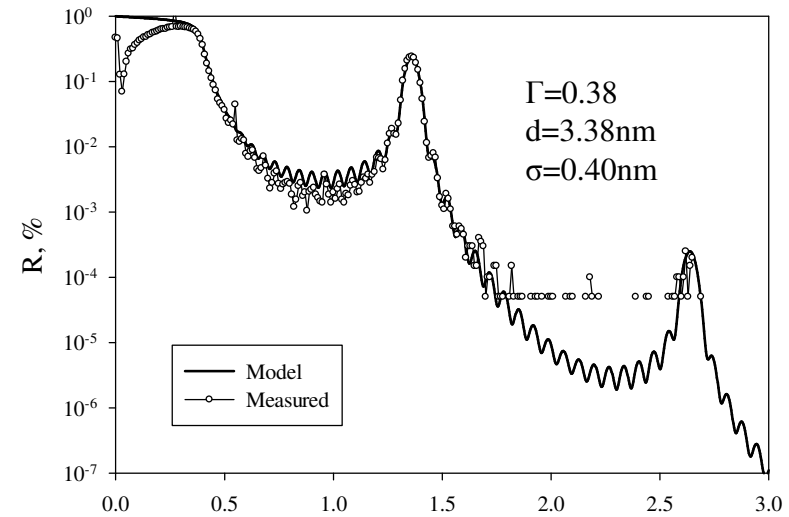
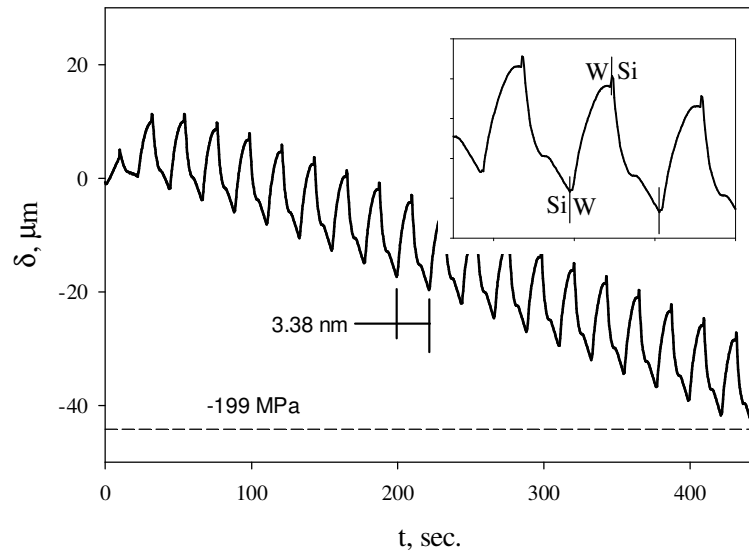
$T_s \sim 27-30^\circ\text{C}$ , 2.5 mTorr Ar  
100 $\mu\text{m}$  thick Schott D263

Calibration masses placed on cantilever tip used to validate substrate modulus and linear range of the sensor:

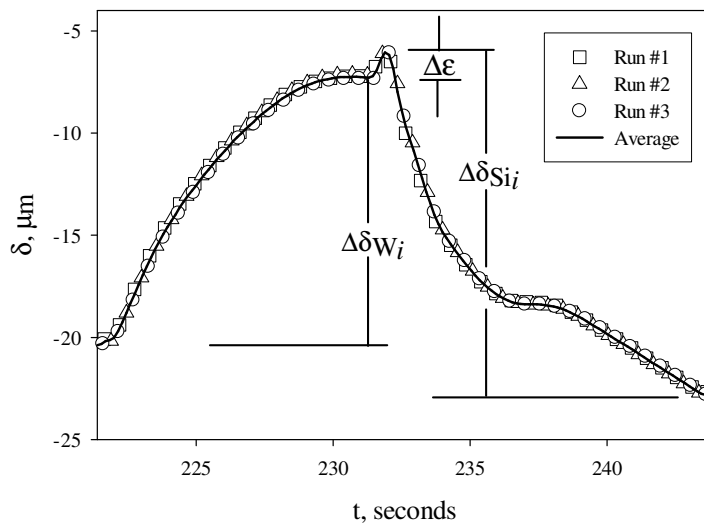
$$\delta_m = \frac{2mgx^2}{E_sbh_s^3} (3L - x)$$



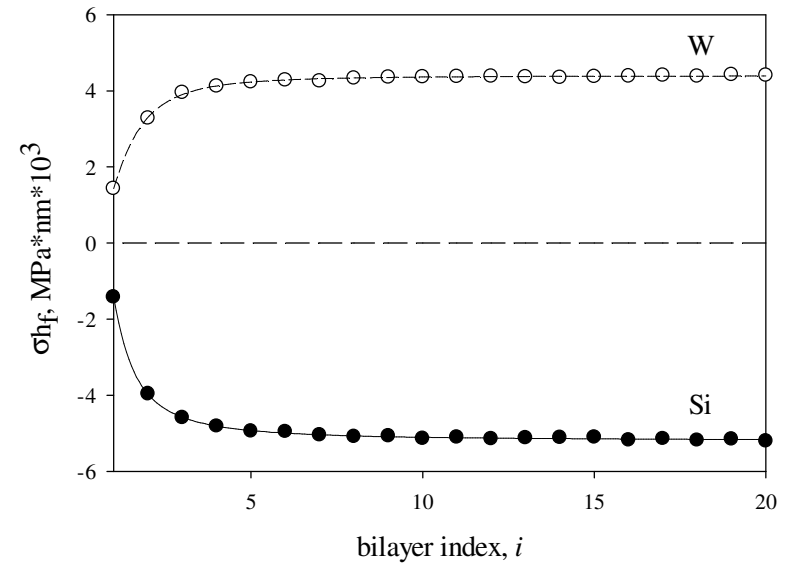
# Device performance



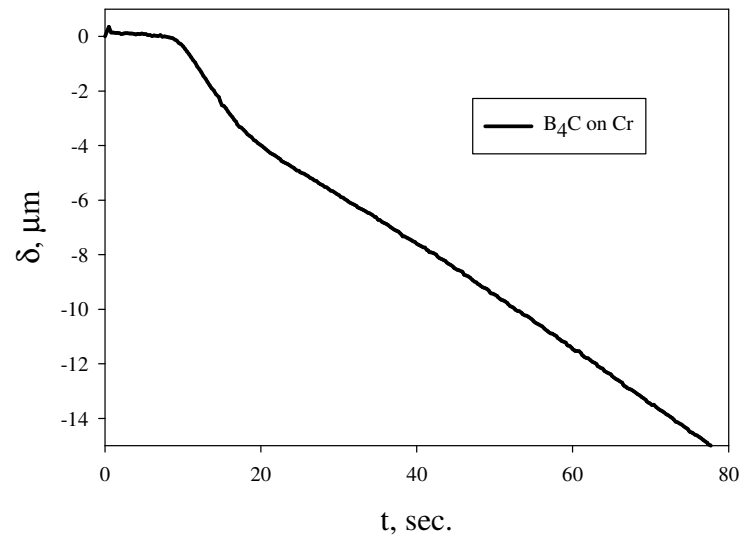
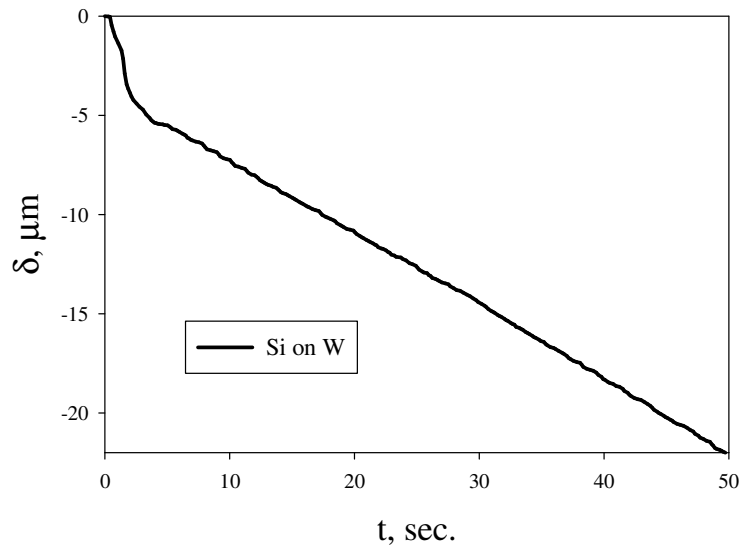
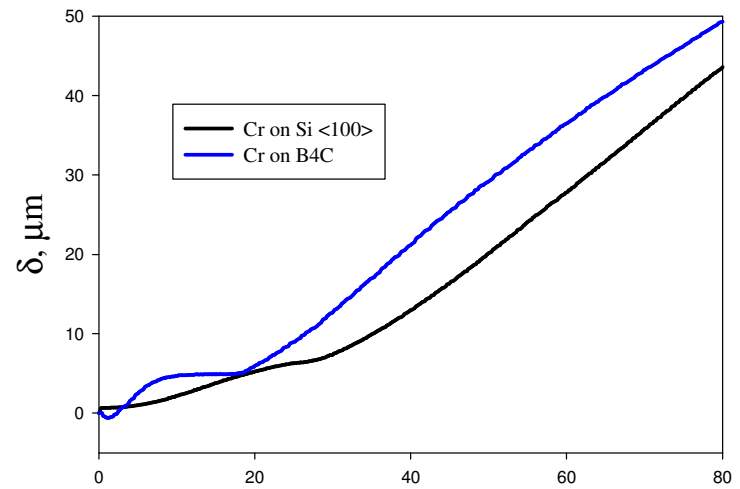
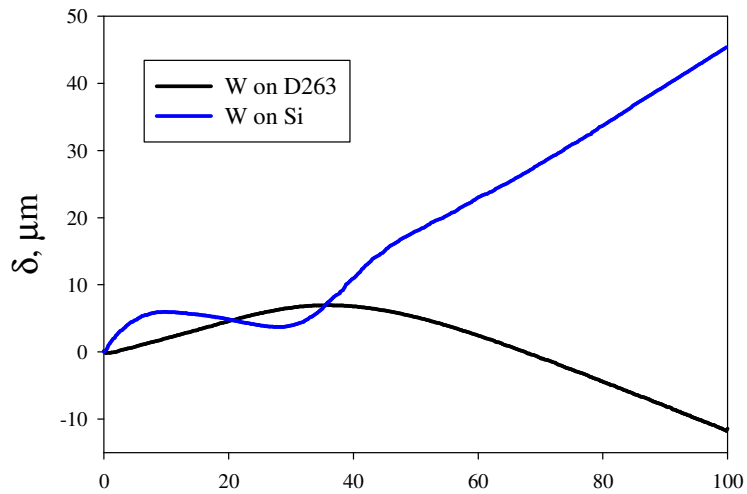
$\pm 2.5\%$  run-to-run repeatability



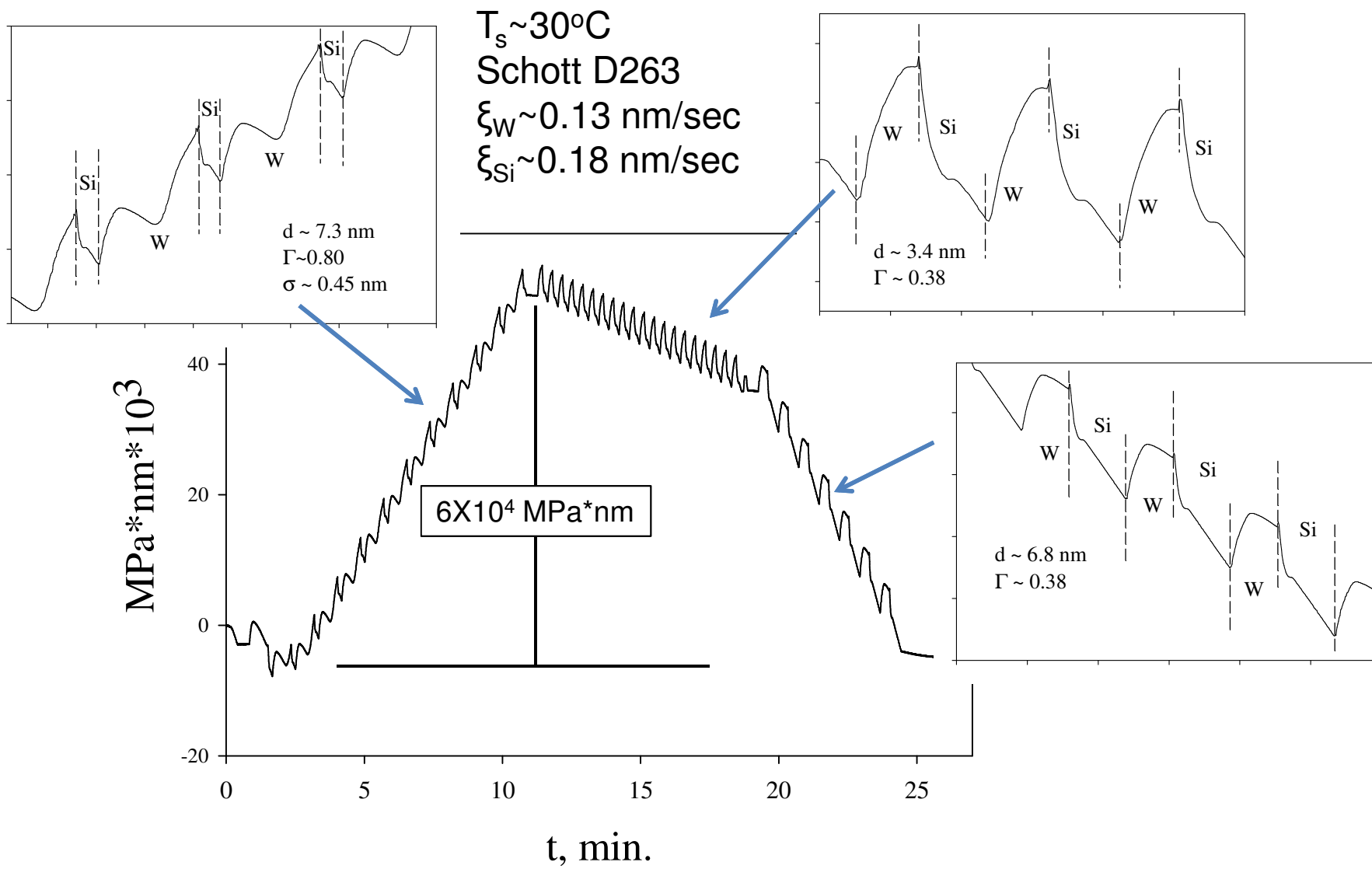
$\pm 0.5\%$  within run repeatability



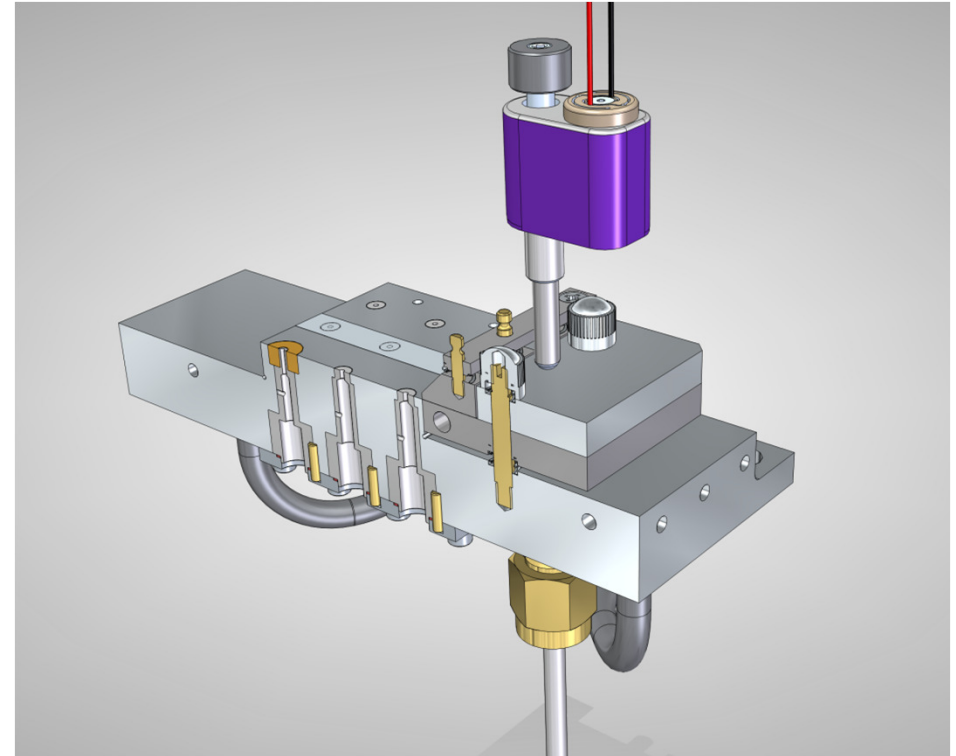
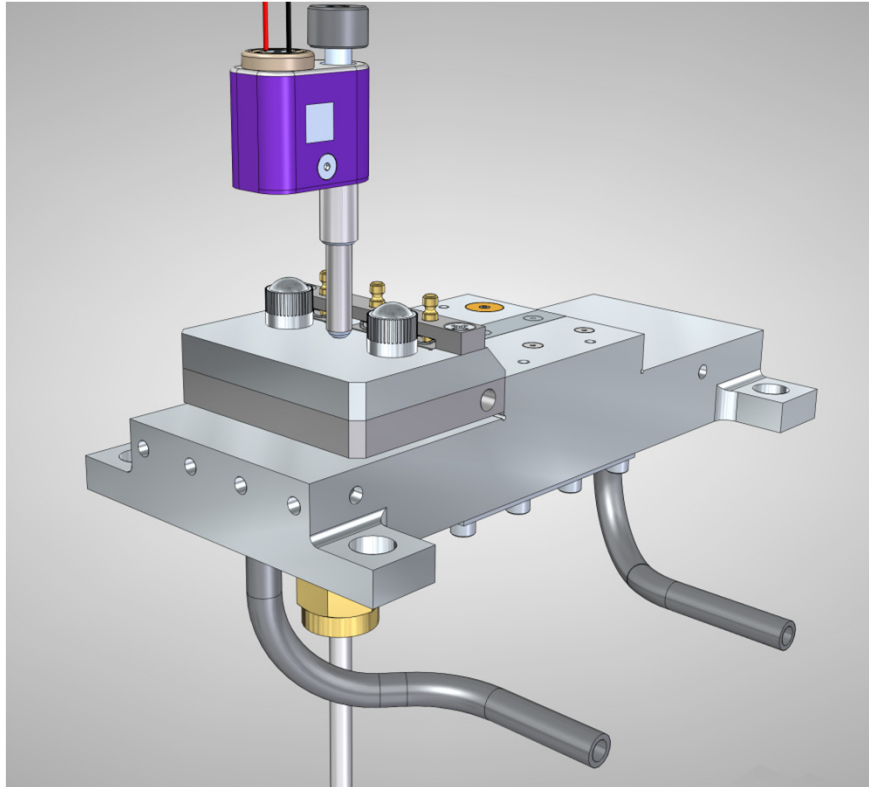
# Effect of material interfaces on the film stress (W, Cr-based)



# In-situ stress in W/Si multilayers



# Second refinement with advanced capability (ongoing)

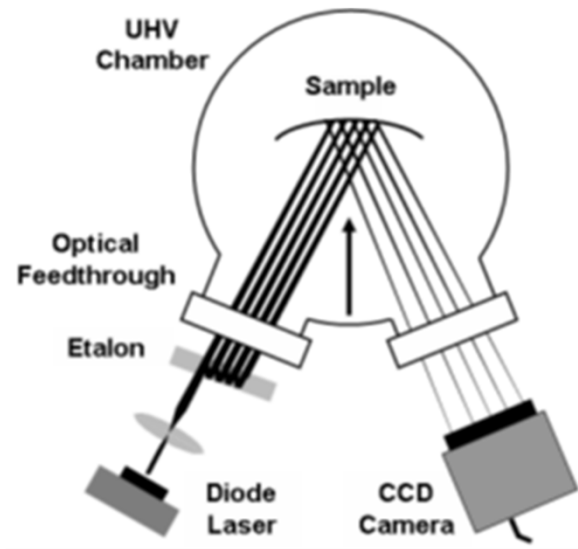


D. Broadway NASA MSFC

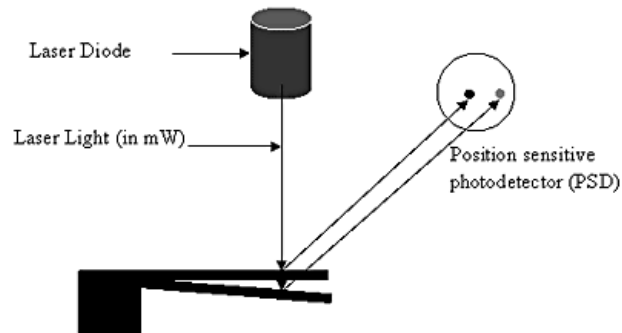
# Comparison to state-of-the-art stress measurement:



Multi-beam stress sensor (MOSS):



Micro cantilever:



## Minimum detectable stress $\Delta\sigma_f$ :

- Ranges from 0.5-50 MPa\*nm depending on method and substrate ( i.e. geometry and mechanical properties)
- MOSS is 50 MPa\*nm for 100  $\mu\text{m}$  thick silicon substrate

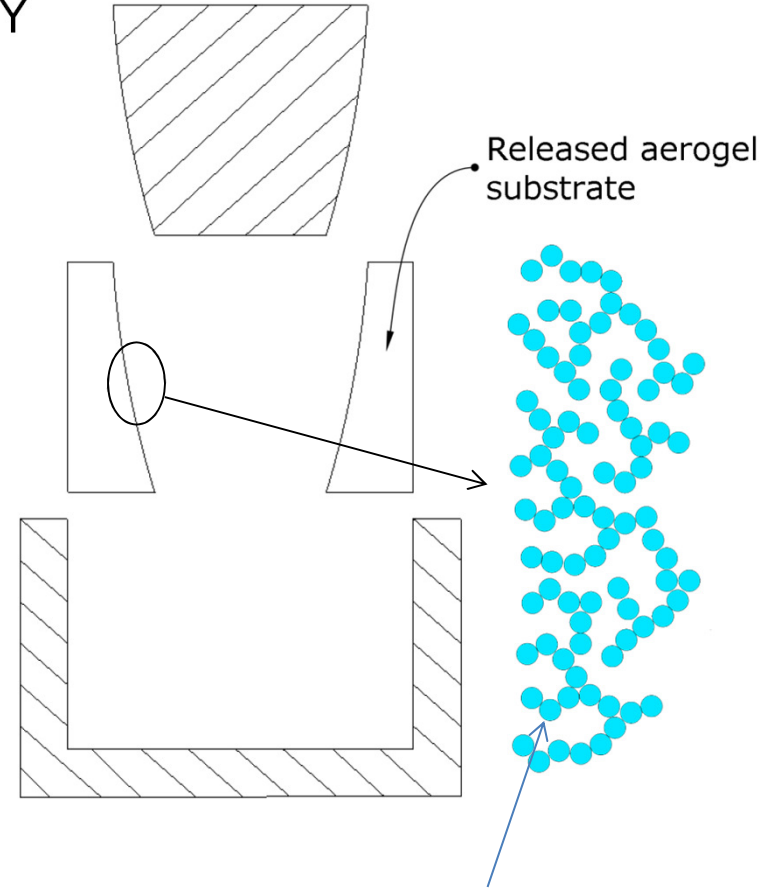
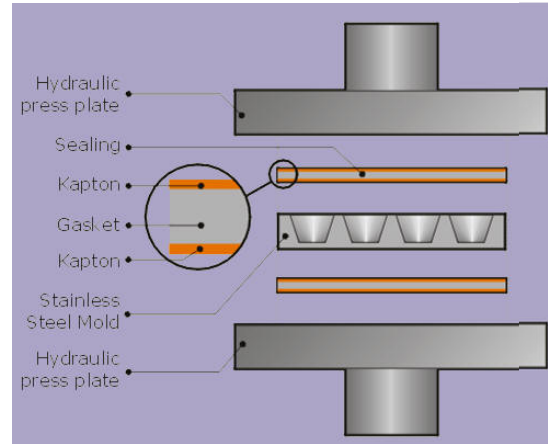
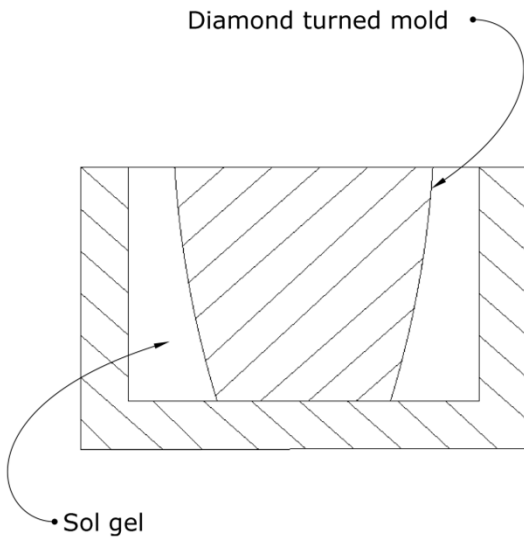
## Draw backs with current optical methods:

- Requires external optical access to the substrate through angled viewports
- Limited to specific deposition geometries
- Complex
- Requires the use of opaque substrates such as crystalline silicon.
- Film side is measured which can result in destructive interference effects when measuring transparent films.



# Replicated silica aerogels for ultra lightweight mirrors

## Rapid supercritical extraction method (RSCE) Partner: Union College NY



2-50 nm pore size

Mixture of precursors and nanoparticles (sol gel)

The gel is a colloidal systems in which a nanostructured network of interconnected particles spans the volume of the liquid.

If the liquid in the gel is simply allowed to evaporate, capillary stress would collapse the gel's delicate solid framework. Therefore, a process of supercritical drying is used.

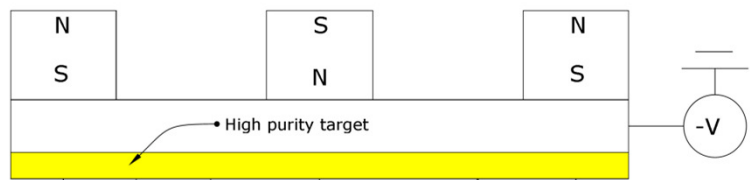
An autoclave is used to heat/pressurize the liquid past its critical point where it is transformed into a supercritical fluid. The supercritical fluid loses all surface tension and can no longer exert capillary stress. Isothermal depressurization at the critical temperature is then used to transform the supercritical fluid to a gas.

Dry, low-density, porous, solid framework of the gel.  
Typically  
95-99% air/vacuum by volume.

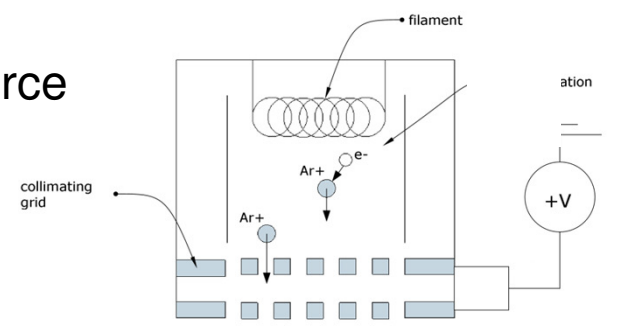


# Planarization, optical coating of areogels

## Magnetron Sputtering



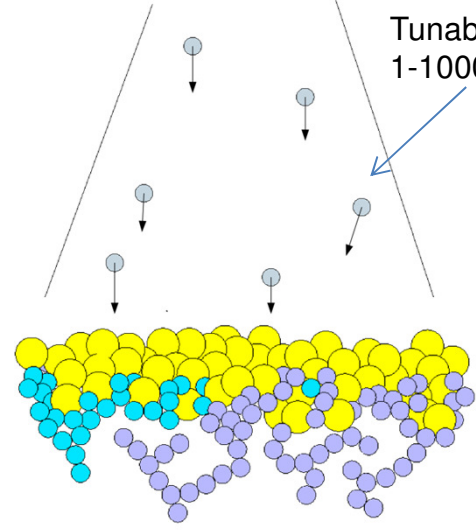
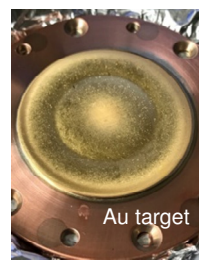
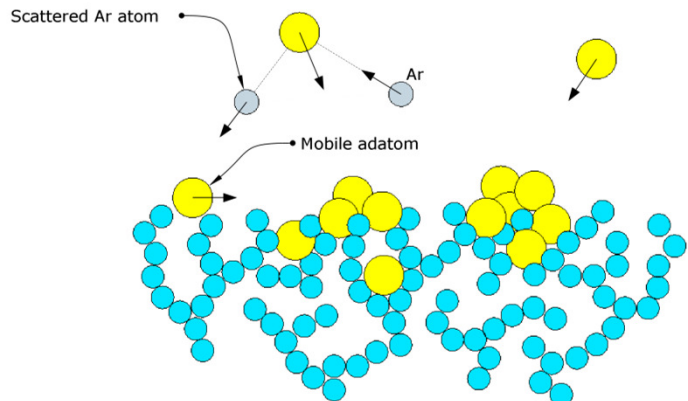
## Ion Source



Ion assisted deposition, ion figuring (optional)



Sequentially or concurrently



Process conditions

- Gas pressure
- Temperature
- Mass of sputtered species

Adatom mobility

Film microstructure  
Film stress

Surface roughness

Optical performance

- Specular reflectivity
- Light Scattering
  - Imaging Resolution

Tolerable micro roughness,  $\sigma$ , increases with wavelength of incident radiation:  $\sigma < 3-5 \text{ \AA}$  for x-rays  
 $< 1-3 \text{ nm}$  for visible light





Thank you!